



# Single Wide Bandwidth Analog Switch

#### **Features**

- Single-Supply Operation (+2V to +6V)
- Rail-to-Rail Analog Signal Dynamic Range
- Low On-Resistance (6-Ohm typical with 5V supply) Minimizes Distortion and Error Voltages
- On-Resistance Flatness, 3-Ohm typical
- Low Charge Injection Reduces Glitch Errors. Q = 4pC (typical)
- · Replaces Mechanical Relays
- High Speed: t<sub>ON</sub> = 10ns typical
- Wide –3dB Bandwidth: 300 MHz (typical)
- High-Current Channel Capability:>100mA
- TTL/CMOS Logic Compatible
- Low Power Consumption (0.5 µW typical)
- Small outline transistor package minimizes board area -65 mil wide SOT23-5 (T5)

### **Applications**

- Audio, Video Switching and Routing
- Battery-Powered Communication Systems
- Computer Peripherals
- · Telecommunications
- · Portable Instrumentation
- · Mechanical Relay Replacement
- · Cell Phones
- PDAs

#### Truth Table

<del>OE</del>	PI5A125
0	ON
1	OFF

Switch shown for Logic "0" input

### **Description**

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The PI5A125 is a single analog switch designed for single-supply operation. This high-precision device is ideal for low-distortion audio, video, signal switching and routing.

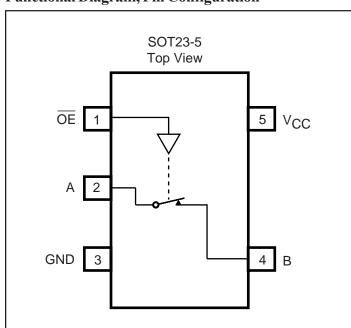
The PI5A125 is a single-pole single-throw (SPST), normally closed (NC) switch. The switch is open when  $\overline{OE}$  is HIGH.

This switch conducts current equally well in either direction when on. When off, it blocks voltages up to  $V_{CC}$ .

The PI5A125 is fully specified with +5V, and +3.3V supplies. With +5V, it guarantees < 10-ohms ON-resistance. ON-resistance flatness is less than 5-ohms over the specified range. The switch also guarantees fast switching speeds (toN <20ns).

This product is available in a 5-pin SOT23 plastic package for operation over the industrial (-40°C to +85°C) temperature range.

## **Functional Diagram, Pin Configuration**





## **Electrical Specifications - Single +5V Supply** ( $V_{CC} = +5V \pm 10\%$ , GND = 0V, $V_{INH} = 2.4V$ , $V_{INL} = 0.8V$ )

Description	Parameter	Conditions	Temp. (°C)	Min. <sup>(2)</sup>	Typ.(1)	Max. <sup>(2)</sup>	Units	
Analog Switch				!				
Analog Signal Range (3)	V <sub>ANALOG</sub>		Full	0		Vcc	V	
On-Resistance	R <sub>ON</sub>	$V_{CC} = 4.5V$ , $I_{B} = -30$ mA, $V_{A} = +2.5V$	25		8	10	Ω	
			Full			18		
(5)		$V_{CC} = 5V$ , $I_B = -30$ mA,	25		2.5	3.5		
On-Resistance Flatness <sup>(5)</sup>	R <sub>FL</sub> AT(ON)	$V_A = 1V, 2.5V, 4V$	Full			4		
Off1 (6)	I <sub>A(OFF)</sub> or	$V_{CC} = 5.5 V_{,} V_{B} = 0 V_{,}$	25		0.20			
Off Leakage Current <sup>(6)</sup>	I <sub>B(OFF)</sub>	$V_A = 4.5V$	Full	-80		80		
On Leelees Comment(6)	I <sub>A(ON)</sub> or	V+ = 5.5V,	25		0.20		- nA	
On Leakage Current <sup>(6)</sup>	I <sub>B(ON)</sub>	$V_{\rm B} = V_{\rm A} = +4.5V$	Full	-80		80		
Logic Input							•	
Input High Voltage	V <sub>IH</sub>	Guaranteed Logic High Level	Full	2			3.7	
Input Low Voltage	V <sub>IL</sub>	Guaranteed Logic Low Level				0.8	V	
Input Current with Input Voltage High	$I_{\mathrm{INH}}$	$V_{IN}$ =2.4V, all others = 0.8V			0.005	1	μА	
Input Current with Input Voltage Low	$I_{\mathrm{INL}}$	$V_{IN}$ =0.8V, all others = 2.4V		-1				
Dynamic							•	
T. 0 T.			25		7	15		
Turn-On Time	Furn-On Time toN	$V_{CC} = 5V$ , see Figure 1	Full			20		
T. OWT		V - 2V - E' - 2	25		1	7	nc	
Turn-Off Time	$t_{ m OFF}$	$V_{COM} = \pm 3V$ , see Figure 2	Full		2	5		
Charge Injection (3)	Q	$C_L = 1 \text{nF}, V_{GEN} = 0 \text{V},$ $R_{GEN} = 0 \Omega$ , see Figure 2				10	pC	
Off Isolation	OIRR	$R_L = 50\Omega$ , $C_L = 5pF$ , f = 10 MHz, see Figure 3	25				dB	
A or B Off Capacitance	C <sub>(OFF)</sub>	f = 1kHz, see Figure 4			5.5		- pF	
On Capacitance	C <sub>(ON)</sub>	f = 1kHz, see Figure 5			5.5			
-3dB Bandwidth	BW	$R_L = 50\Omega$ , see Figure 6			300		MHz	
Supply			1					
Power-Supply Range	V <sub>CC</sub>			2		6	V	
Positive Supply Current	$I_{CC}$	$V+=5.5V$ , $V_{\rm IN}=0V$ or $V_{\rm CC}$ , All channels on or off	Full			1	μА	

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### Absolute Maximum Ratings

Voltages Referenced to GND	
V <sub>CC</sub> 0.5V to+	·7V
$V_{OE}, V_A, V_B{}^{(1)}$ 0.5V to $V_{CC}$ +	2V
or 30mA, whichever occurs f	ĭrst
Current (any terminal except A, B)	mΑ
Current: A,B (pulsed at 1ms, 10% duty cycle) 120	mΑ

#### **Thermal Information**

Continuous Power Dissipation	
SOT23-5 (derate 7mW/°C above +70°C)	550mW
Storage Temperature65°C to	+150°C
Lead Temperature (soldering, 10s)	+300°C

#### Note 1:

Signals on  $\overline{OE}$ , A, B exceeding Vcc or GND are clamped by internal diodes. Limit forward diode current to 30mA.

**Caution**: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.

### Electrical Specifications-Single +3.3V Supply $(V_{CC} = +3.3V \pm 10\%, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V)$

Parameter	Symbol	Conditions	Temp(°C)	Min.(1)	<b>Typ.</b> <sup>(2)</sup>	Max. <sup>(1)</sup>	Units
Analog Switch							
Analog Signal Range <sup>(3)</sup>	V <sub>ANALOG</sub>			0		V <sub>CC</sub>	V
On-Resistance	D	V2V I 20mA V -15V	25		12	18	
	R <sub>ON</sub>	$V_{CC} = 3V$ , $I_B = -30mA$ , $V_A = 1.5V$	Full			28	Ω
On-Resistance Flatness <sup>(3,5)</sup>	R <sub>FLAT(ON)</sub>	$V_{CC} = 3.3V$ , $I_B = -30mA$ ,	25		0.5	4	
	$V_A = 0.8V, 2.5V$	$V_A = 0.8V, 2.5V$	Full			5	
Dynamic							
Turn-On Time	$t_{ON}$ $V_{CC} = 3.3 V$ to $V_{NO}$		25		15	25	
Turn-On Time		Full			40		
Turn-Off Time	toff	or VNC = 1.5V, Fig.1	25		1.5	12	ns
			Full			20	
Charge Injection <sup>(3)</sup>	Q	$C_L = 1$ nf, $V_{GEN} = 0$ V, $R_{GEN} = 0$ V, Fig.2	25		1.3	10	рC
Supply							
$I_{CC}$	Positive Supply Current	$V_{CC} = 3.6V$ , $V_{IN} = 0V$ or $V_{CC}$ All channels on or off	Full			1	μА

#### **Notes:**

1. The algebraic convention, where the most negative value is a minimum and the most positive is a maximum, is used in this data sheet.

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- 2. Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.
- 3. Guaranteed by design
- 4.  $\Delta R_{ON} = R_{ON} \max R_{ON} \min$
- 5. Flatness is defined as the difference between the maximum and minimum value of on-resistance measured.
- 6. Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at +25°C.
- 7. Off Isolation =  $20\log_{10} V_B / V_A$ . See Figure 3.



## **Test Circuits/Timing Diagrams**

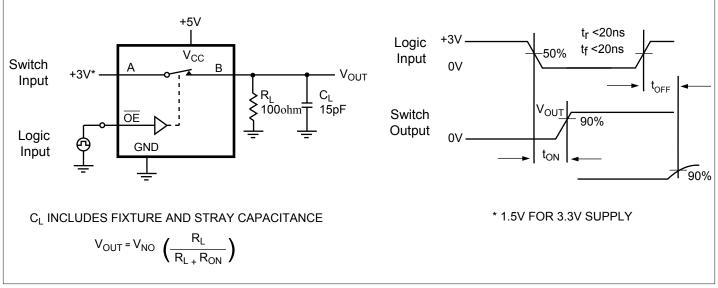


Figure 1. Switching Time

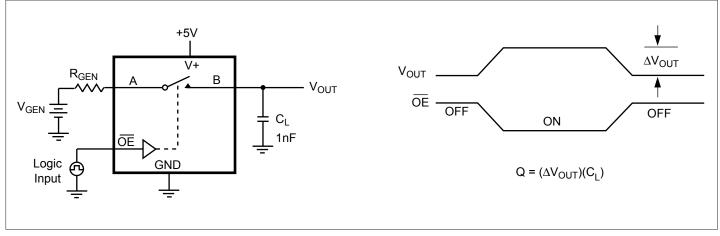


Figure 2. Charge Injection

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## Test Circuits/Timing Diagrams (continued)

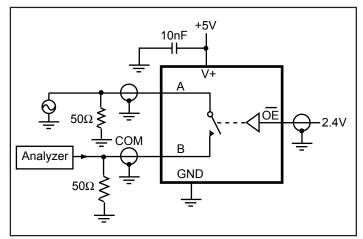


Figure 3. Off Isolation

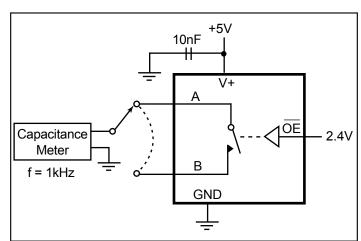


Figure 4. Channel-Off Capacitance

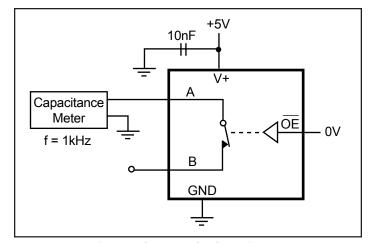


Figure 5. Channel-On Capacitance

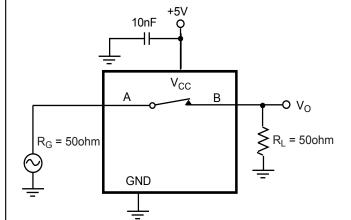


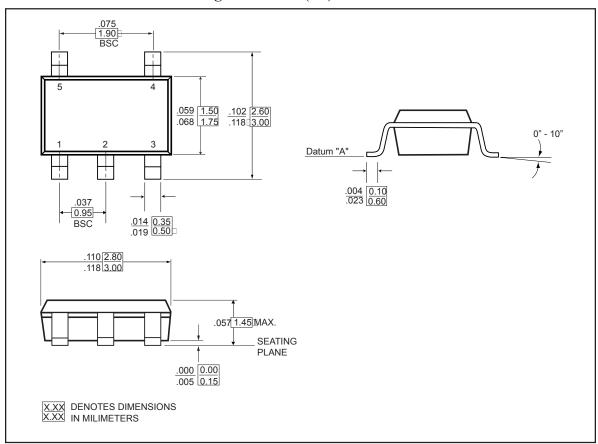
Figure 6. Bandwidth

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## Small Outline Transistor Package - SOT23-5 (T5)



## **Ordering Information**

P/N	Package		
PI5A125TX	SOT23-5		